EECS170A Fall2006 Final Exam Solution

12/5/2006 4:00 to 6:00pm Professor Peter Burke

PROBLEM ONE: (32 points)

- A) D V has the same shape as the bands except it's upside-down.
- B) E Electric field = dE/dx, i.e. proportional to the slope of the bands.
- C) A E_F is constant.
- D) C $E_F E_V < 3KT$ near x = L.
- E) B or D $E_i E_F = E_i / 2 E_i / 3 = E_i / 6$
 - $p = n_i \exp[(E_i E_F) / KT]$ = 10¹⁰ e [1.12/(6x0.0259)] = 1.35 x10¹³/cm³

Since no calculators allowed, hence we accept answer D as correct answer, although B is the correct answer.

F) A	Under equilibrium, $J_N = 0$
G) B	$J_{Pldrift} = q\mu_p p\epsilon = q\mu_p p \; x \; (1/q.dE/dx) = E_G \; / \; qL$
H) C	K.E. = $E_V (L) - E_{Hole} = E_G / 3$

Grading criteria: 4 points for each correct answer.

PROBLEM TWO: (36 points)

Question	True	False
А		Х
В	Х	
С		Х
D	Х	
Е	Х	
F		Х
G	Х	
Н	Х	
Ι		Х

Grading criteria: 4 points for each correct answer.

PROBLEM THREE: (8 points)

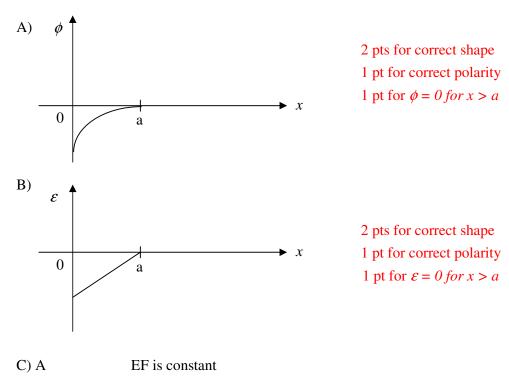
The diode is forward biased.

It's because $p_n(x = x_n) > p_{n0} = n_i^2/N_D$ and $n_p(x = -x_p) > n_{p0} = n_i^2/N_A$. That is, there are accumulations of minority carriers at the edges of the depletion region.

Grading criteria: - 4pts for stating "forward biased".

- No credits for answers just mentioning the energy band diagram.
- No credits for just mentioning current flow but not the carriers.
- No credits for just mentioning p_p and n_n only.
- 3 pts for mentioning increases in p_n and n_p , but did not mention at the edges of the depletion region.
- 4 pts for mentioning increases in p_n and n_p at the edges of the depletion region.
- 2 pts for only mentioning diffusions of electrons and holes across the depletion region to the other side of the junction.
- 2 pts for stating p_n increases, but n_p decreases.

PROBLEM FOUR: (24 points)



D) B or C or A

Since no calculators allowed, hence we accept answer A and C as correct answers, although B is the correct answer.

E) C F) B

Grading criteria: 4 points for each correct answer.